

Vishay Semiconductors

Dual Photovoltaic MOSFET Driver Solid State Relay



DESCRIPTION

The VO1263AB/AAC photovoltaic MOSFET driver consists of two LEDs optically coupled to two photodiode arrays. The photodiode array provides a floating source with adequate voltage and current to drive high-power MOSFET transistors. Optical coupling provides a high I/O isolation voltage. In order to turn the MOSFET off, an external resistance (gate-to-source) is required for gate discharge.

FEATURES

- · High open circuit voltage, up to 14.6 V typical
- High short circuit current, up to 42 μA typical
- Isolation test voltage 5300 V_{BMS}
- Logic compatible input
- High reliability
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

APPLICATIONS

- High-side driver
- · Solid state relays
- · Floating power supply
- Power control
- Data acquisition
- ATE
- · Isolated switching

Note See "solid state relays" (application note 56)

AGENCY APPROVALS

UL1577:	file no. E52744 system code H or J, double protection
DIN EN:	60747-5-5

CUL: file no. E52744, equivalent to CSA bulletin 5A

ORDER INFORMATION					
PART	REMARKS	PACKAGE			
VO1263AAC	Tubes	SMD-8			
VO1263AACTR	Tape and reel	SMD-8			
VO1263AB	Tubes	DIP-8			

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
SSR							
LED input ratings continous forward current		l _F	50	mA			
LED input ratings reverse voltage	$I_R \le 10 \ \mu A$	V _R	5.0	V			
Photodiode array reverse voltage	$I_R \le 2.0 \ \mu A$	V _R	100	V			
Ambient operating temperature range		T _{amb}	- 40 to + 100	°C			
Storage temperature range		T _{stg}	- 40 to + 150	°C			
Pin soldering temperature ⁽²⁾	t = 7.0 s max.	T _{sld}	270	°C			
Input to output isolation voltage	t = 60 s min.	V _{ISO}	5300	V _{RMS}			

Notes

⁽¹⁾ $T_{amb} = 25$ °C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽²⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

Document Number: 84639 For technical questions, please contact: <u>optocoupler.answers@vishay.com</u> Rev. 1.6, 07-May-08





COMPLIAN





ELECTRICAL CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
LED forward voltage	I _F = 10 mA	V _F	1.2	1.3	1.6	V
Detector reverse voltage	I _R = 2.0 μA	V _{R(PDA)}		350		V
	I _F = 5.0 mA	V _{OC}		13.3		V
	l _F = 10 mA	V _{OC}	10.3	13.8	16.5	V
Open circuit voltage (pins 5, 6 or 7, 8)	l _F = 15 mA	V _{OC}		14		V
	I _F = 20 mA	V _{OC}		14.3		V
	l _F = 30 mA	V _{OC}		14.6		V
	I _F = 5.0 mA	I _{SC}	3.0	6.0		μA
	l _F = 10 mA	I _{SC}	7.5	15		μA
Short circuit current (pins 5, 6 or 7, 8)	l _F = 15 mA	I _{SC}	11	22		μA
	I _F = 20 mA	I _{SC}	15	30		μA
	I _F = 30 mA	I _{SC}	21	42		μΑ

Note

 $T_{amb} = 25 \ ^{\circ}C$, unless otherwise specified.

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification (according to IEC 68 part 1)				40/100/21		
Comparative tracking index		CTI	175		399	
V _{IOTM}			8000			V
V _{IORM}			630			V
P _{SO}					500	mW
I _{SI}					300	mA
T _{SI}					175	°C
Creepage distance			7			mm
Clearance distance			7			mm

FUNCTIONAL DESCRIPTION

Figure 1 outlines the IV characteristics of the illuminated photodiode array (PDA). For operation at voltages below V_{OC} , the PDA acts as a nearly constant current source. The actual region of operation depends upon the load.

The amount of current applied to the LED (pins 1 and 2 or 3 and 4) determines the amount of light produced for the PDA. For high temperature operation, more LED current may be required.



Dual Photovoltaic MOSFET Driver Solid Vishay Semiconductors State Relay

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified



Fig. 1 - Short Circuit Current vs. Open Circuit Voltage



Fig. 2 - Output Voltage vs. LED Current







Fig. 4 - Short Circuit Current vs. Temperature



Fig. 5 - Open Circuit Voltage vs. Temperature





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Fig. 7 - Typical Dual Form A Solid State Relay Application



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State Relay

PACKAGE DIMENSIONS in inches (millimeters)





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State Relay



OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

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